

# BLS9G2735S-15G

Power LDMOS transistor

Rev. 1 — 23 July 2019

AMPLEON

Product data sheet

## 1. Product profile

### 1.1 General description

15 W LDMOS power transistor for S-band applications in the frequency range from 2700 MHz to 3500 MHz.

**Table 1. Typical performance**

RF performance at  $T_{case} = 25\text{ }^{\circ}\text{C}$ ;  $t_p = 100\text{ }\mu\text{s}$ ;  $\delta = 10\text{ }\%$ ;  $I_{Dq} = 70\text{ mA}$ ; in a common source class-AB production test circuit.

| Test signal | f            | $I_{Dq}$ | $V_{DS}$ | $P_L$ | $G_p$ | $\eta_D$ |
|-------------|--------------|----------|----------|-------|-------|----------|
|             | (MHz)        | (mA)     | (V)      | (W)   | (dB)  | (%)      |
| pulsed RF   | 2700 to 3100 | 70       | 32       | 15    | 14    | 55       |
|             | 3100 to 3500 | 70       | 32       | 15    | 14    | 52       |
|             | 3100         | 70       | 32       | 15    | 14    | 59       |

### 1.2 Features and benefits

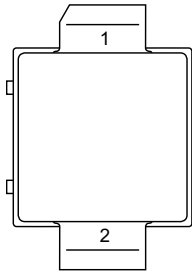
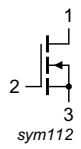
- High efficiency
- Integrated ESD protection
- Excellent ruggedness
- Excellent thermal stability
- Designed for broadband operation in S-band radar applications
- Internally matched for ease of use
- For RoHS compliance see the product details on the Ampleon website

### 1.3 Applications

- RF power amplifiers for S-band radar applications in the 2700 MHz to 3500 MHz frequency range

## 2. Pinning information

Table 2. Pinning

| Pin | Description           | Simplified outline   | Graphic symbol  |
|-----|-----------------------|--|---|
| 1   | drain                 |  |  |
| 2   | gate                  |  |   |
| 3   | source <sup>[1]</sup> |  |   |

[1] Connected to flange.

## 3. Ordering information

Table 3. Ordering information

| Type number    | Package |  |         |
|----------------|---------|--|---------|
|                | Name    | Description                              | Version |
| BLS9G2735S-15G | -       | earless flanged ceramic package; 2 leads | SOT975C |

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol    | Parameter            | Conditions     | Min | Max  | Unit |
|-----------|----------------------|----------------|-----|------|------|
| $V_{DS}$  | drain-source voltage |                | -   | 65   | V    |
| $V_{GS}$  | gate-source voltage  |                | -6  | +13  | V    |
| $T_{stg}$ | storage temperature  |                | -65 | +150 | °C   |
| $T_j$     | junction temperature | <sup>[1]</sup> | -   | 225  | °C   |

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

## 5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol        | Parameter  | Conditions  | Typ | Unit |
|---------------|--|---|-----|------|
| $Z_{th(j-c)}$ | transient thermal resistance from junction to case | $T_{case} = 80\text{ °C}; P_L = 15\text{ W}$          |     |      |
|               |  | $t_p = 100\text{ }\mu\text{s}; \delta = 10\text{ }\%$ | 1.3 | K/W  |
|               |  | $t_p = 200\text{ }\mu\text{s}; \delta = 10\text{ }\%$ | 1.6 | K/W  |
|               |  | $t_p = 300\text{ }\mu\text{s}; \delta = 10\text{ }\%$ | 1.8 | K/W  |
|               |  | $t_p = 500\text{ }\mu\text{s}; \delta = 10\text{ }\%$ | 2.1 | K/W  |
|               |  | $t_p = 100\text{ }\mu\text{s}; \delta = 20\text{ }\%$ | 1.7 | K/W  |

## 6. Characteristics

**Table 6. DC characteristics**

$T_j = 25\text{ °C}$  per section; unless otherwise specified.

| Symbol        | Parameter                        | Conditions  | Min | Typ  | Max | Unit             |
|---------------|----------------------------------|---|-----|------|-----|------------------|
| $V_{(BR)DSS}$ | drain-source breakdown voltage   | $V_{GS} = 0\text{ V}; I_D = 0.11\text{ mA}$                 | 65  | -    | -   | V                |
| $V_{GS(th)}$  | gate-source threshold voltage    | $V_{DS} = 10\text{ V}; I_D = 10.5\text{ mA}$                | 1.5 | 2    | 2.5 | V                |
| $I_{DSS}$     | drain leakage current            | $V_{GS} = 0\text{ V}; V_{DS} = 32\text{ V}$                 | -   | -    | 1.4 | $\mu\text{A}$    |
| $I_{DSX}$     | drain cut-off current            | $V_{GS} = V_{GS(th)} + 3.75\text{ V}; V_{DS} = 10\text{ V}$ | -   | 2.2  | -   | A                |
| $I_{GSS}$     | gate leakage current             | $V_{GS} = 11\text{ V}; V_{DS} = 0\text{ V}$                 | -   | -    | 140 | nA               |
| $g_{fs}$      | forward transconductance         | $V_{DS} = 10\text{ V}; I_D = 0.53\text{ A}$                 | -   | 0.78 | -   | S                |
| $R_{DS(on)}$  | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75\text{ V}; I_D = 368\text{ mA}$  | -   | 1200 | -   | $\text{m}\Omega$ |

**Table 7. RF characteristics**

Test signal: pulsed RF;  $t_p = 100\text{ }\mu\text{s}$ ;  $\delta = 10\%$  at  $V_{DS} = 32\text{ V}; I_{Dq} = 70\text{ mA}; T_{case} = 25\text{ °C}$ ; unless otherwise specified; in a class-AB production circuit measured at frequency of 3100 MHz.

| Symbol    | Parameter         | Conditions          | Min  | Typ | Max | Unit |
|-----------|-------------------|---------------------|------|-----|-----|------|
| $G_p$     | power gain        | $P_L = 15\text{ W}$ | 11.5 | 14  | -   | dB   |
| $RL_{in}$ | input return loss | $P_L = 15\text{ W}$ | -    | -11 | -   | dB   |
| $\eta_D$  | drain efficiency  | $P_L = 15\text{ W}$ | 52   | 59  | -   | %    |

## 7. Test information

### 7.1 Ruggedness in class-AB operation

The BLS9G2735S-15G is capable of withstanding a load mismatch corresponding to  $V_{SWR} = 10 : 1$  through all phases under the following conditions:  $V_{DS} = 32\text{ V}; I_{Dq} = 70\text{ mA}; P_L = 15\text{ W}$  (pulsed CW);  $f = 2900\text{ MHz}$ .

## 7.2 Impedance information

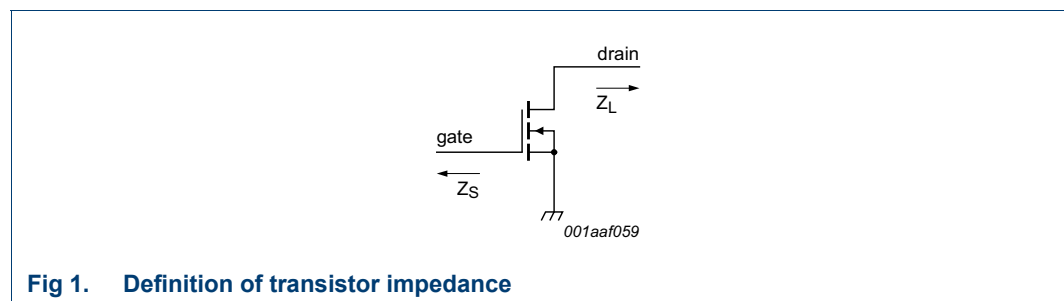
**Table 8. Typical impedance**

Measured load-pull data of device;  $I_{Dq} = 70 \text{ mA}$  (main);  $V_{DS} = 32 \text{ V}$ ; pulsed CW ( $t_p = 100 \mu\text{s}$ ;  $\delta = 10 \%$ ).

| f                                    | $Z_S$ [1]    | $Z_L$ [1]    | $P_L$ [2] | $\eta_D$ [2] | $G_p$ [2] |
|--------------------------------------|--------------|--------------|-----------|--------------|-----------|
| (MHz)                                | ( $\Omega$ ) | ( $\Omega$ ) | (W)       | (%)          | (dB)      |
| <b>Maximum power load</b>            |              |              |           |              |           |
| 2700                                 | 1.9 – j10.0  | 7.2 – j3.3   | 15.5      | 55.9         | 17.5      |
| 2800                                 | 2.2 – j10.8  | 7.2 – j4.0   | 15.2      | 54.8         | 18.1      |
| 2900                                 | 2.5 – j11.8  | 6.5 – j5.1   | 15.9      | 56.4         | 18.3      |
| 3000                                 | 2.9 – j13.3  | 6.2 – j6.0   | 15.7      | 56.5         | 18.9      |
| 3100                                 | 4.5 – j15.2  | 6.2 – j7.2   | 16.4      | 56.9         | 19.2      |
| 3200                                 | 6.7 – j15.4  | 6.7 – j7.7   | 15.6      | 54.7         | 19.1      |
| 3300                                 | 9.5 – j15.8  | 6.9 – j8.5   | 16.1      | 55.4         | 19.0      |
| 3400                                 | 13.5 – j12.0 | 6.6 – j9.1   | 15.4      | 54.6         | 19.2      |
| 3500                                 | 13.0 – j7.4  | 7.0 – j10.0  | 15.6      | 54.3         | 18.9      |
| <b>Maximum drain efficiency load</b> |              |              |           |              |           |
| 2700                                 | 1.9 – j10.0  | 4.8 – j1.4   | 12.8      | 60.1         | 19.7      |
| 2800                                 | 2.2 – j10.8  | 3.6 – j2.6   | 12.5      | 61.2         | 19.9      |
| 2900                                 | 2.5 – j11.8  | 3.7 – j3.7   | 13.3      | 62.7         | 20.1      |
| 3000                                 | 2.9 – j13.3  | 3.7 – j4.5   | 12.8      | 61.9         | 21.1      |
| 3100                                 | 4.5 – j15.2  | 3.9 – j5.6   | 13.5      | 62.5         | 21.3      |
| 3200                                 | 6.7 – j15.4  | 4.1 – j6.6   | 13.3      | 59.9         | 20.7      |
| 3300                                 | 9.5 – j15.8  | 3.8 – j7.7   | 13.2      | 60.5         | 21.2      |
| 3400                                 | 13.5 – j12.0 | 4.3 – j8.2   | 13.0      | 57.8         | 20.8      |
| 3500                                 | 13.0 – j7.4  | 4.2 – j9.5   | 13.0      | 57.7         | 20.4      |

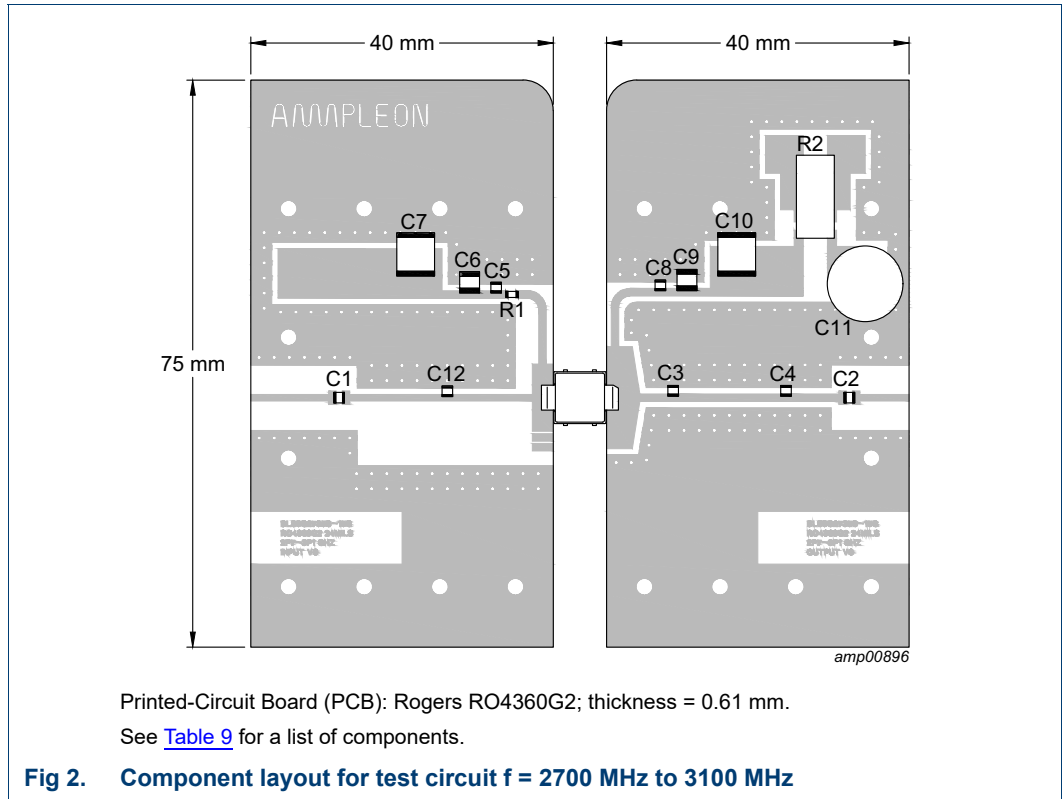
[1]  $Z_S$  and  $Z_L$  defined in [Figure 1](#).

[2] at 3 dB gain compression.



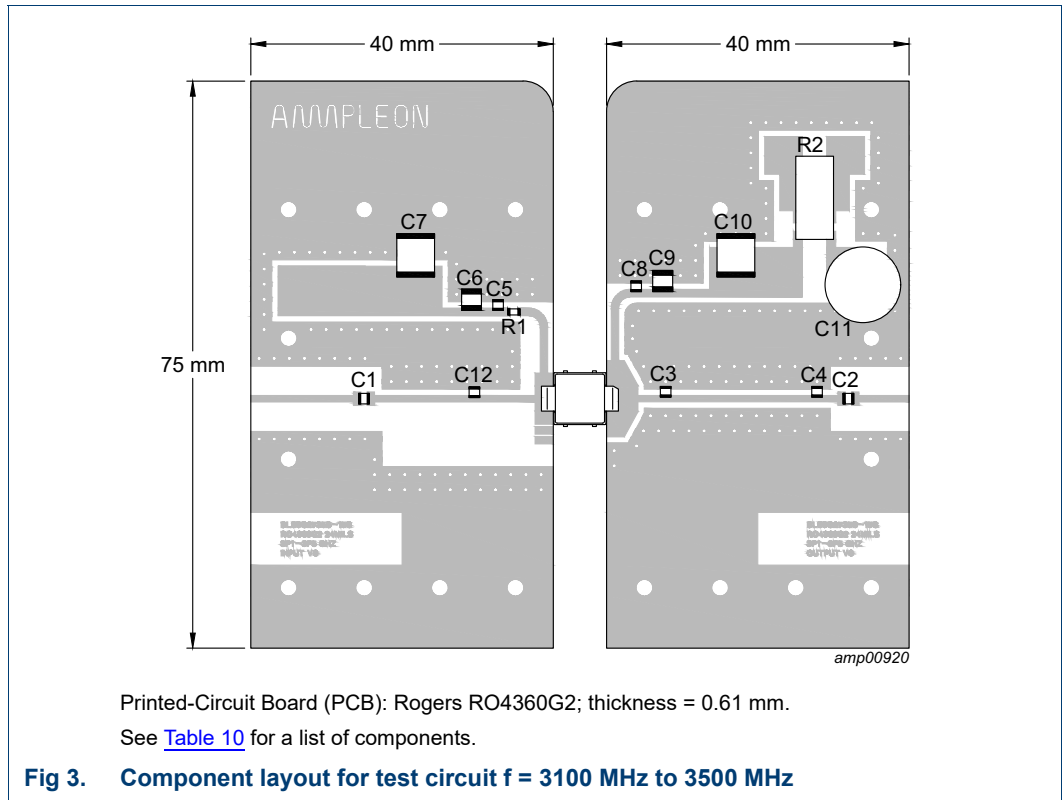
**Fig 1. Definition of transistor impedance**

7.3 Test circuit



**Table 9. List of components**  
See [Figure 2](#) for component layout.

| Component | Description                       | Value              | Remarks |
|-----------|-----------------------------------|--------------------|---------|
| C1        | multilayer ceramic chip capacitor | 1 pF               |         |
| C2        | multilayer ceramic chip capacitor | 4.7 pF             |         |
| C3        | multilayer ceramic chip capacitor | 1.1 pF             |         |
| C4        | multilayer ceramic chip capacitor | 0.1 pF             |         |
| C5, C8    | multilayer ceramic chip capacitor | 15 pF              |         |
| C6, C9    | multilayer ceramic chip capacitor | 1 nF               |         |
| C7, C10   | multilayer ceramic chip capacitor | 10 $\mu\text{F}$   |         |
| C11       | electrolytic capacitor            | 1000 $\mu\text{F}$ |         |
| C12       | multilayer ceramic chip capacitor | 0.8 pF             |         |
| R1        | SMD resistor                      | 5 $\Omega$         |         |
| R2        | current sense resistor            | 5 m $\Omega$       |         |

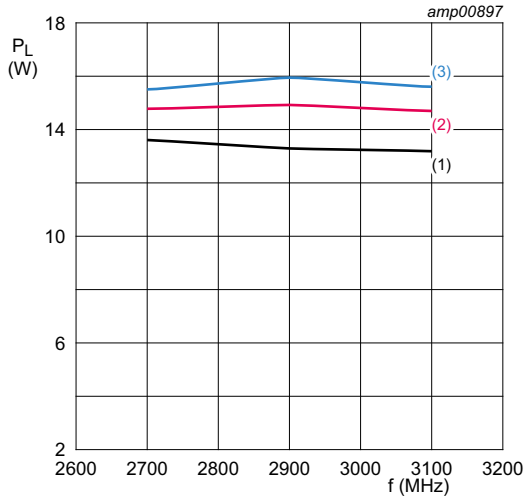


**Table 10. List of components**  
See [Figure 3](#) for component layout.

| Component | Description                       | Value              | Remarks |
|-----------|-----------------------------------|--------------------|---------|
| C1        | multilayer ceramic chip capacitor | 22 pF              |         |
| C2        | multilayer ceramic chip capacitor | 4.7 pF             |         |
| C3        | multilayer ceramic chip capacitor | 0.5 pF             |         |
| C4        | multilayer ceramic chip capacitor | 0.1 pF             |         |
| C5, C8    | multilayer ceramic chip capacitor | 15 pF              |         |
| C6, C9    | multilayer ceramic chip capacitor | 1 nF               |         |
| C7, C10   | multilayer ceramic chip capacitor | 10 $\mu\text{F}$   |         |
| C11       | electrolytic capacitor            | 1000 $\mu\text{F}$ |         |
| C12       | multilayer ceramic chip capacitor | 0.5 pF             |         |
| R1        | SMD resistor                      | 5 $\Omega$         |         |
| R2        | current sense resistor            | 5 m $\Omega$       |         |

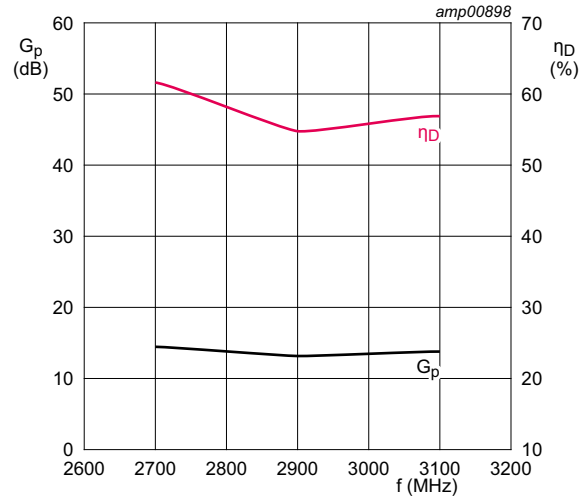
7.4 Graphical data

7.4.1 Pulsed CW; f = 2700 MHz to 3100 MHz



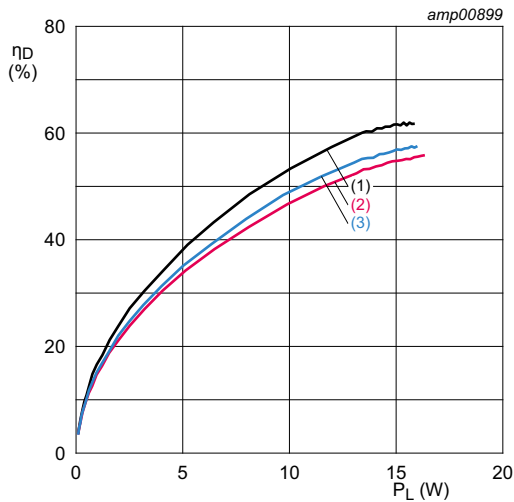
$V_{DS} = 32\text{ V}; I_{Dq} = 70\text{ mA}; t_p = 100\text{ }\mu\text{s}; \delta = 10\text{ }\%$   
 (1) at  $P_{L(1dB)}$   
 (2) at  $P_{L(2dB)}$   
 (3) at  $P_{L(3dB)}$

**Fig 4. Output power as a function of frequency; typical values**



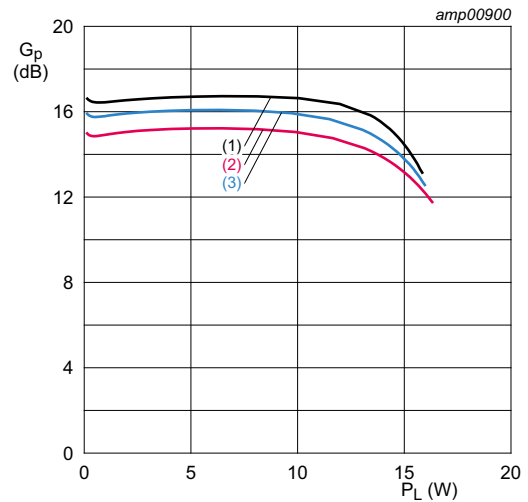
$V_{DS} = 32\text{ V}; I_{Dq} = 70\text{ mA}; P_L = 15\text{ W}; t_p = 100\text{ }\mu\text{s}; \delta = 10\text{ }\%$

**Fig 5. Power gain and drain efficiency as function of frequency; typical values**



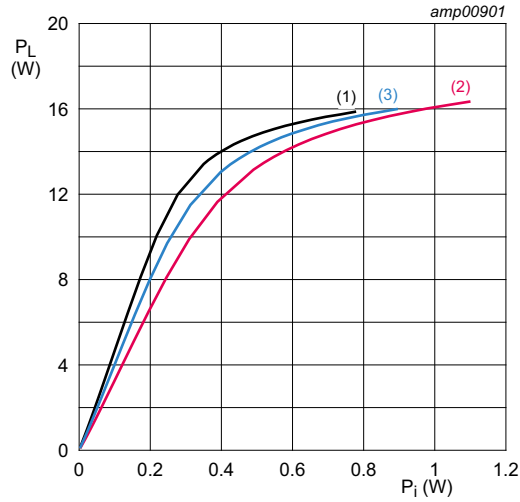
$V_{DS} = 32\text{ V}; I_{Dq} = 70\text{ mA}; t_p = 100\text{ }\mu\text{s}; \delta = 10\text{ }\%$   
 (1) f = 2700 MHz  
 (2) f = 2900 MHz  
 (3) f = 3100 MHz

**Fig 6. Drain efficiency as a function of output power; typical values**



$V_{DS} = 32\text{ V}; I_{Dq} = 70\text{ mA}; t_p = 100\text{ }\mu\text{s}; \delta = 10\text{ }\%$   
 (1) f = 2700 MHz  
 (2) f = 2900 MHz  
 (3) f = 3100 MHz

**Fig 7. Power gain as a function of output power; typical values**

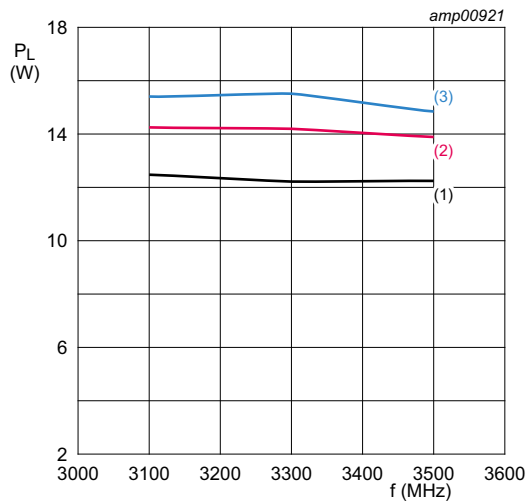


$V_{DS} = 32\text{ V}$ ;  $I_{Dq} = 70\text{ mA}$ ;  $t_p = 100\ \mu\text{s}$ ;  $\delta = 10\ \%$ .

- (1)  $f = 2700\text{ MHz}$
- (2)  $f = 2900\text{ MHz}$
- (3)  $f = 3100\text{ MHz}$

Fig 8. Output power as a function of input power; typical values

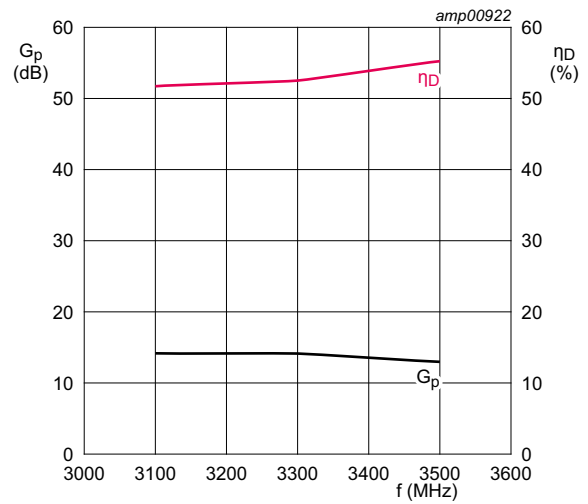
7.4.2 Pulsed CW;  $f = 3100\text{ MHz to } 3500\text{ MHz}$



$V_{DS} = 32\text{ V}$ ;  $I_{Dq} = 70\text{ mA}$ ;  $t_p = 100\ \mu\text{s}$ ;  $\delta = 10\ \%$ .

- (1) at  $P_{L(1dB)}$
- (2) at  $P_{L(2dB)}$
- (3) at  $P_{L(3dB)}$

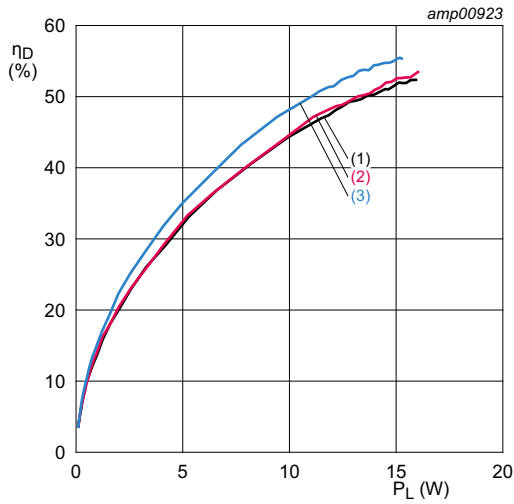
Fig 9. Output power as a function of frequency; typical values



$V_{DS} = 32\text{ V}$ ;  $I_{Dq} = 70\text{ mA}$ ;  $P_L = 15\text{ W}$ ;  $t_p = 100\ \mu\text{s}$ ;  $\delta = 10\ \%$ .

Fig 10. Power gain and drain efficiency as function of frequency; typical values

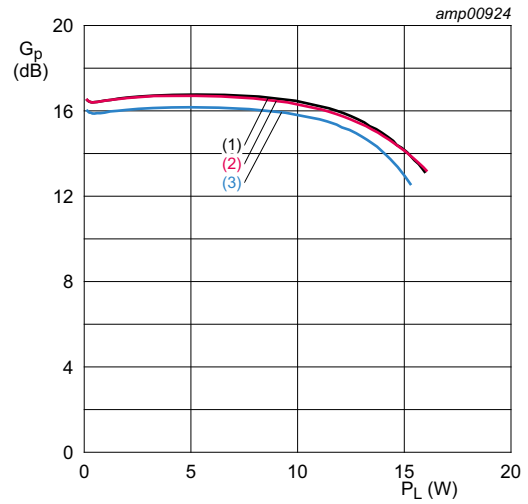




$V_{DS} = 32\text{ V}; I_{Dq} = 70\text{ mA}; t_p = 100\ \mu\text{s}; \delta = 10\ \%$ .

- (1)  $f = 3100\text{ MHz}$
- (2)  $f = 3300\text{ MHz}$
- (3)  $f = 3500\text{ MHz}$

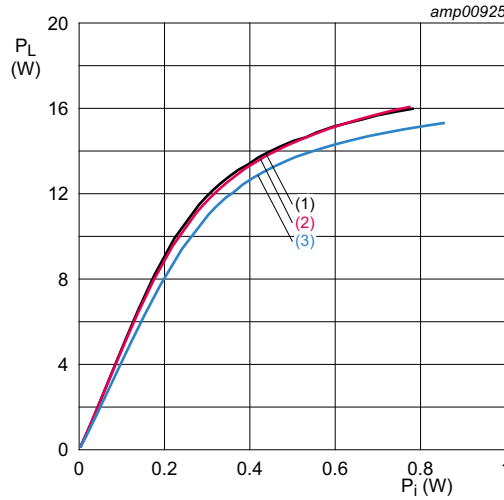
**Fig 11. Drain efficiency as a function of output power; typical values**



$V_{DS} = 32\text{ V}; I_{Dq} = 70\text{ mA}; t_p = 100\ \mu\text{s}; \delta = 10\ \%$ .

- (1)  $f = 3100\text{ MHz}$
- (2)  $f = 3300\text{ MHz}$
- (3)  $f = 3500\text{ MHz}$

**Fig 12. Power gain as a function of output power; typical values**



$V_{DS} = 32\text{ V}; I_{Dq} = 70\text{ mA}; t_p = 100\ \mu\text{s}; \delta = 10\ \%$ .

- (1)  $f = 3100\text{ MHz}$
- (2)  $f = 3300\text{ MHz}$
- (3)  $f = 3500\text{ MHz}$

**Fig 13. Output power as a function of input power; typical values**

8. Package outline

Earless flanged ceramic package; 2 leads

SOT975C

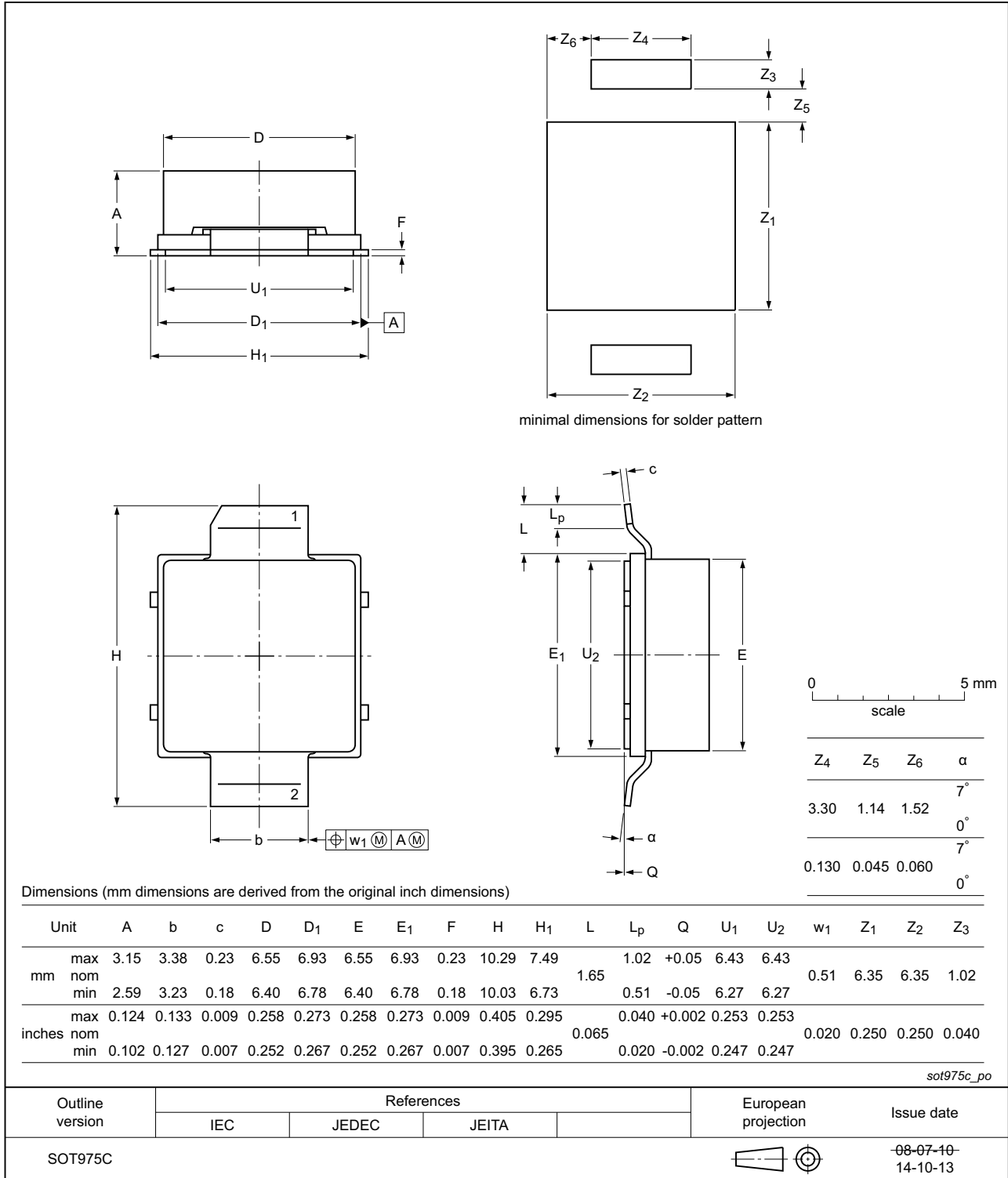


Fig 14. Package outline SOT975C

## 9. Handling information

**CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

**Table 11. ESD sensitivity**

| ESD model  | Class                   |
|--|-------------------------|
| Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002 | C2A <a href="#">[1]</a> |
| Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001     | 2 <a href="#">[2]</a>   |

[1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

## 10. Abbreviations

**Table 12. Abbreviations**

| Acronym | Description                                  |
|---------|--|
| CW      | Continuous Wave                              |
| ESD     | ElectroStatic Discharge                      |
| LDMOS   | Laterally Diffused Metal-Oxide Semiconductor |
| MTF     | Median Time to Failure                       |
| RoHS    | Restriction of Hazardous Substances          |
| S-band  | Short wave band                              |
| SMD     | Surface Mounted Device                       |
| VSWR    | Voltage Standing Wave Ratio                  |

## 11. Revision history

**Table 13. Revision history**

| Document ID        | Release date | Data sheet status  | Change notice | Supersedes |
|--------------------|--------------|--------------------|---------------|------------|
| BLS9G2735S-15G v.1 | 20190723     | Product data sheet | -             | -          |

## 12. Legal information

### 12.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.ampleon.com>.

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## 13. Contact information

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Date of release: 23 July 2019

Document identifier: BLS9G2735S-15G